Thick Film Hybrid IC

STK400-090



AF Power Amplifier (Split Power Supply) (50W+50W+50W min, THD = 0.4%)

Overview

The STK400-090 is a thick-film audio power amplifier IC belonging to a series in which all devices are pin compatible. This allows a single PCB design to be used to construct amplifiers of various output capacity simply by changing hybrid ICs. Also, this series is part of a new, larger series that comprises mutually similar devices with the same pin compatibility. This makes possible the development of a 2-channel amplifier from a 3-channel amplifier using the same PCB. In addition, this new series features $6/3\Omega$ drive in order to support the low impedance of modern speakers.

Features

· Pin compatible STK400-000 series (3-channel/single package)

STK401-000 series (2-channel/single package)

- Output load impedance $R_L = 6/3\Omega$ supported
- New pin configuration

Pin configuration has been grouped into individual blocks of inputs, outputs and supply lines, minimizing the adverse effects of pattern layout on operating characteristics.

- Few external components
- In comparison with existing series, external bootstrap resistors and capacitors can be eliminated.

Specifications

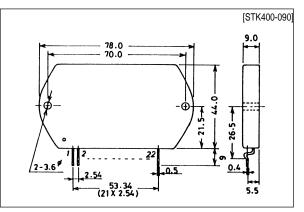
Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		±47	V
Thermal resistance	Өј-с	Per power transistor	1.7	°C/W
Junction temperature	Tj		150	°C
Operating substrate temperature	Tc		125	°C
Storage temperature	Tstg		-30 to +125	°C
Available time for load short-circuit	t _s	$V_{CC} = \pm 32V, R_L = 6\Omega,$ f = 50Hz, P _O = 50W	1	s

Package Dimensions

unit: mm

4086A



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Parameter	Symbol	Conditions	min	typ	max	Unit
Quiescent current	I _{cco}	V _{CC} = ±39V	30	90	150	mA
Output power	P _O (1)	$V_{CC} = \pm 32V$, f = 20Hz to 20kHz, THD = 0.4%	50	55	_	W
	P _O (2)	$V_{CC} = \pm 26V$, f = 1kHz, THD = 1.0%, R _L = 3 Ω	50	55	_	W
Total harmonic distortion	THD(1)	$V_{CC} = \pm 32V$, f = 20Hz to 20kHz, P _O = 1.0W	_	_	0.4	%
	THD(2)	V _{CC} = ±32V, f = 1kHz, P _O = 5.0W	-	0.01	_	%
Frequency response	f _L , f _H	$V_{CC} = \pm 32V, P_{O} = 1.0W, {}^{+0}_{-3} dB$	-	20 to 50k	-	Hz
Input impedance	r _i	V _{CC} = ±32V, f = 1kHz, P _O = 1.0W	-	55	_	kΩ
Output noise voltage	V _{NO}	V_{CC} = ±39V, Rg = 10k Ω	-	-	1.2	mVrms
Neutral voltage	V _N	V _{CC} = ±39V	-70	0	+70	mV

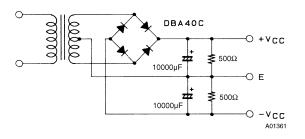
Operating Characteristics at Ta = 25°C, $R_L = 6\Omega$ (noninductive load), $Rg = 600\Omega$, VG = 40dB

Notes.

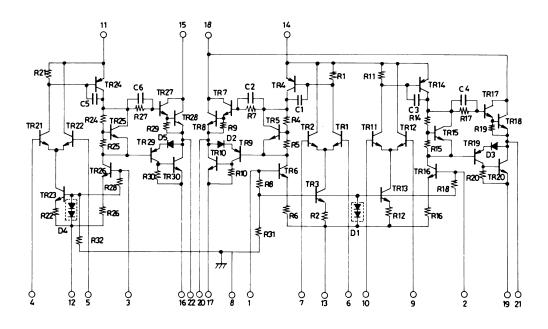
All tests are measured using a constant-voltage supply unless otherwise specified.

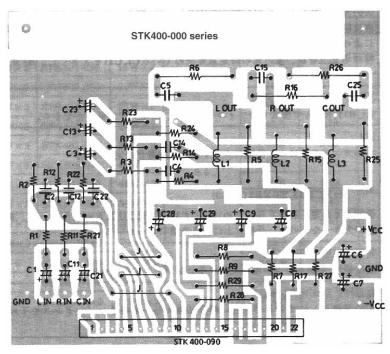
Available time for load short-circuit and output noise voltage are measured using the transformer supply specified below. The output noise voltage is the peak value of an average-reading meter with an rms value scale (VTVM). A regulated AC supply (50Hz) should be used to eliminate the effects of AC primary line flicker noise.

Specified Transformer Supply (MG-200 or Equivalent)



Equivalent Circuit





Sample PCB Layout for 2-Channel or 3-Channel Amplifiers

+ **Vcc** R28 100 C 28 100 R8 100 # C6 10u R11 C11 1k 2.2µ C ch INPUT O C INPUT Rch 9 6 0.1 0.1 R26: 4.7µ R16 R6 4.7 R14 56k R13 560 R29 R14 R9 100 29 1004 ± ± ± ± ± ± ± ± ± ± ± to ↓ to : C29 100 µ C13 . -₩cc Unit (resistance: Ω , capacitance: F)

Sample Application Circuit

Copper (Cu) foil surface Pin 1 of STK401-000 series devices corresponds to pin 6 of STK400-000 series devices.

External Component Description

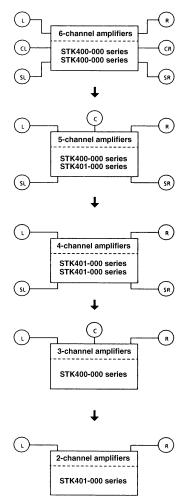
C1, C11, C21	Input coupling capacitors. For DC blocking. Since capacitor reactance becomes larger at lower frequencies, the output noise can be adversely affected by signal source resistance-dependent 1/f noise. In this case, a lower reactance value should be chosen. In order to remove pop noise at power-on, larger values of capacitance should be chosen for C1 and C11, which determine the input time constant, and smaller values for C3, C13 and C23 in the NF circuit.
C2, C12, C22	Input filter capacitors. These, together with R1, R11 and R21, form filters to reduce high-frequency noise.
C3, C13, C23	NF capacitors. These determine the low-side cut-off frequency. $f_{L} = \frac{1}{2\pi \times C3(C13, C23) \times R3(R13, R23)}$ Large values should be chosen for C3, C13 and C23 to maintain voltage gain at low frequencies. However, because this would tend to increase the shock noise at power-on, values larger than absolutely necessary should be avoided.
C5, C15, C25	Oscillation prevention capacitors. Mylar capacitors are recommended for their excellent thermal and frequency characteristics.
C6, C7	Oscillation prevention capacitors. These should be inserted as close as possible to the IC supply pins to reduce supply impedance and hence provide stable IC operation. Electrolytic capacitors are recommended.
C8, C9, C28, C29	Decoupling capacitors. These, together with R8, R9, R28 and R29, form time constant circuits that remove shock noise and ripple voltage from the supply, preventing any noise being coupled to the inputs.
R1, R11, R21	Input filter resistors.
R2, R12, R22	Input bias resistors. These are used to bias the input pins at zero potential. The input impedance is largely determined by this resistance.
R3, R13, R23 R4, R14, R24	Voltage-gain VG setting resistors. VG = 40dB is recommended using R3, R13, R23 = 560Ω , and R4, R14, R24 = $56k\Omega$. Gain adjustments are best made using R3, R13 and R23. If gain adjustments are made using R4, R14 and R24, then set R2, R12, R22 = R4, R14, R24 to maintain V _N balance stability.
R5, R15, R25	Oscillation prevention resistors.
R6, R16, R26	Oscillation prevention resistors. The power dissipated in these resistors is dependent on the frequency, as given below. P R6 (R16, R26) = $\left(\frac{V_{CC} \max/\sqrt{2}}{1/2\pi f \times C5(C15,C25) + R6(R16,R26)}\right)^2 \times R6(R16,R26)$ where f is the output signal frequency upper limit.
R8, R9, R28, R29	Ripple filter resistors. P _O max, ripple rejection and supply power-on shock noise are all affected by this resistance. These resistors should be chosen taking into consideration both the function they perform as predriver transistor limiting resistors during load short circuits and the peak current that flows through them when charging C8, C9, C28 and C29.
L1, L2, L3	Oscillation prevention coils. These correct the phase difference caused by capacitive loads and increase stability against oscillation.

3-channel Rated		2-channel	Rated	THD [%]	Supply voltage [V] ¹					
amplifier type output	output	amplifier type	output		V _{CC} max1	V _{CC} max2	V _{CC} 1	V _{CC} 2		
STK400-010	$10W \times 3$	STK401-010	$10W \times 2$		-	<u>+2</u> 6	±17	±14		
STK400-020	15W imes 3	STK401-020	$15W \times 2$	0.4	-	±29	±20	±16		
STK400-030	$20W \times 3$	STK401-030	$20W \times 2$			-	±34	±23	±19	
STK400-040	25W imes 3	STK401-040	$25W \times 2$		-	±36	±25	<u>+2</u> 1		
STK400-050	$30W \times 3$	STK401-050	$30W \times 2$		0.4	-	±39	±26	<u>+22</u>	
STK400-060	35W × 3	STK401-060	35W×2			-	±41	<u>+28</u>	<u>+2</u> 3	
STK400-070	40W imes 3	STK401-070	$40W \times 2$			-	±44	±30	<u>+2</u> 4	
STK400-080	45W imes 3	STK401-080	$45W \times 2$				-	±45	±31	±25
STK400-090	50W × 3	STK401-090	50W × 2				-	±47	±32	<u>+2</u> 6
STK400-100	$60W \times 3$	STK401-100	$60W \times 2$				-	±51	±35	<u>+2</u> 7
STK400-110	$70W \times 3$	STK401-110	70W × 2			±56.0	-	±38	-	
-	-	STK401-120	$80W \times 2$				±61.0	-	±42	-
-	-	STK401-130	100W×2				±65.0	-	±45	-
-	-	STK401-140	$120W \times 2$		±74.0	-	±51	-		

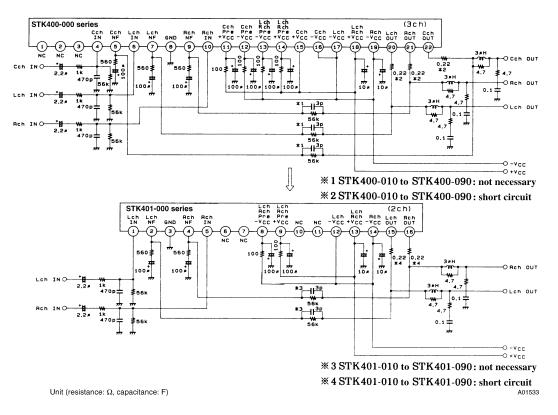
Series Configuration

1. V_{CC} max1 (R_L = 6 Ω), V_{CC} max2 (R_L = 3 to 6 Ω), V_{CC}1 (R_L = 6 Ω), V_{CC}2 (R_L = 3 Ω)

Sample Designs using a Common PCB



External Circuit Diagram



Heatsink Design Considerations

The heatsink thermal resistance, θ c-a, required to dissipate the STK400-090 device total power dissipation, Pd, is determined as follows:

Condition 1: IC substrate temperature not to exceed 125°C.

$$Pd \times \theta c - a + Ta < 125^{\circ}C \dots (1)$$

where Ta is the guaranteed maximum ambient temperature.

Condition 2: Power transistor junction temperature, Tj, not to exceed 150°C.

$$Pd \times \theta c - a + Pd/N \times \theta j - c + Ta < 150^{\circ}C$$
(2)

where N is the number of power transistors and θ j-c is the power transistor thermal resistance per transistor. Note that the power dissipated per transistor is the total, Pd, divided evenly among the N power transistors.

Expressions (1) and (2) can be rewritten making θ c-a the subject.

$\theta c - a < (125 - Ta)/Pd$ (1)'	
$\theta c - a < (150 - Ta)/Pd - \theta i - c/N$	

The heatsink required must have a thermal resistance that simultaneously satisfies both expressions.

The heatsink thermal resistance can be determined from (1)' and (2)' once the following parameters have been defined.

- · Supply voltage
- Load resistance
- · Guaranteed maximum ambient temperature

The total device power dissipation when STK400-090 $V_{CC} = \pm 32V$ and $R_L = 6\Omega$, for a continuous sine wave signal, is a maximum of 105W, as shown in Figure 1.

When estimating the power dissipation for an actual audio signal input, the rule of thumb is to select Pd corresponding to $1/10 P_O$ max (within safe limits) for a continuous sine wave input. For example, from Figure 1,

Pd = 66.5W (for 1/10 P_O max = 5W)

The STK400-090 has 6 power transistors, and the thermal resistance per transistor, θj -c, is 1.7°C/W. If the guaranteed maximum ambient temperature, Ta, is 50°C, then the required heatsink thermal resistance, θc -a, is:

From expression (1)': θc-a < (125 – 50)/66.5 < 1.12

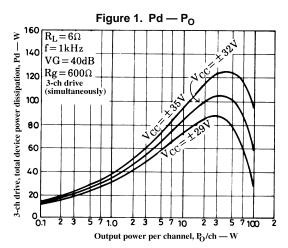
From expression (2)':
$$\theta$$
c-a < (150 - 50)/66.5 - 1.7/6
< 1.22

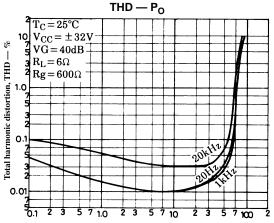
Therefore, to satisfy both expressions, the required heatsink must have a thermal resistance less than 1.12°C/W. Similarly, when STK400-090 V_{CC} = ± 26 V and R_L = 3 Ω , from Figure 2:

Pd = 76W (for 1/10 $P_O max = 5W$)

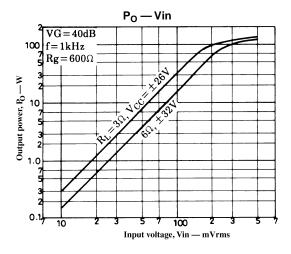
From expression (1)': θc-a < (125 – 50)/76 < 0.98

From expression (2)': θ c-a < (150 – 50)/76 – 1.7/6 < 1.03



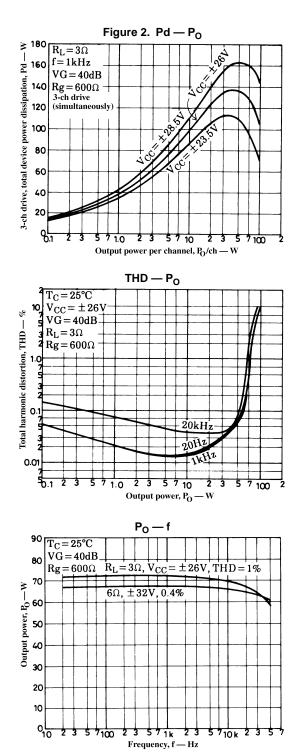


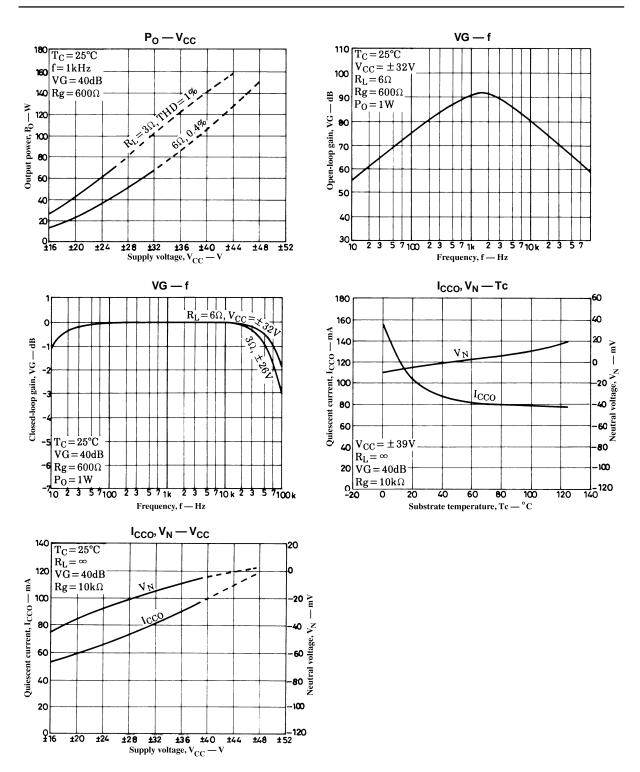
Output power, P_O — W



Therefore, to satisfy both expressions, the required heatsink must have a thermal resistance less than 0.98°C/W.

This heatsink design example is based on a constant-voltage supply, and should be verified within your specific set environment.





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